

## Description

The XT3D4V5B TVS diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebooks, and PDA's. It offers superior electrical characteristics such as low clamping voltage, low leakage current and high surge capability. It is designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lighting.

The XT3D4V5B is in a SOD-323 package and will protect one bidirectional line. It may be used to provide ESD protection up to  $\pm 30\text{kV}$  (Contact and air discharge) according to IEC61000-4-2 , and withstand peak pulse current up to 160A (8/20 $\mu\text{s}$ ) according to IEC61000-4-5.

## Features

- ◆ Working voltage: 4.5V
- ◆ SOD323 Package
- ◆ 3200 Watts peak pulse power ( $t_p=8/20\mu\text{s}$ )
- ◆ Transient protection for data lines to  
IEC 61000-4-2 (ESD)  $\pm 30\text{kV}$  (air),  
 $\pm 30\text{kV}$  (contact)
- IEC 61000-4-5 (Surge) 160A (8/20 $\mu\text{s}$ )
- IEC61000-4-4(EFT)40A(5/50ns)
- ◆ Low leakage current
- ◆ Low clamping voltage
- ◆ Solid-state silicon-avalanche technology

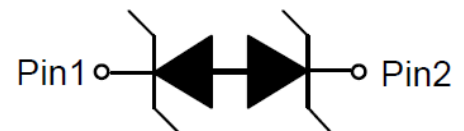
## Applications

- ◆ Power lines
- ◆ Personal digital assistants (PDA's)
- ◆ Microprocessors based equipment
- ◆ Notebooks, Desktops, and Servers
- ◆ Cell phone Handsets and Accessories
- ◆ Portable Electronics
- ◆ Peripherals

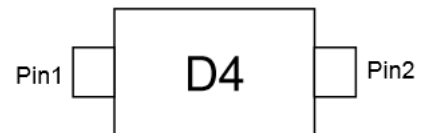
<http://www.xihangsemi.com>



**SOD-323**



**Circuit Diagram**



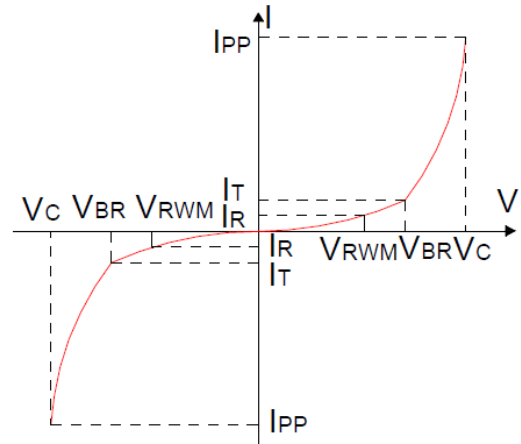
**Marking**

## Order Information

Device	Package	Shipping
XT3D4V5B	SOD-323	3000/Tape&Reel

## Definitions of electrical characteristics

Symbol	Parameter
$V_{RWM}$	Reverse Stand-off Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Reverse Breakdown Voltage @ $I_T$
$I_R$	Reverse Breakdown Current
$I_{PP}$	Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$



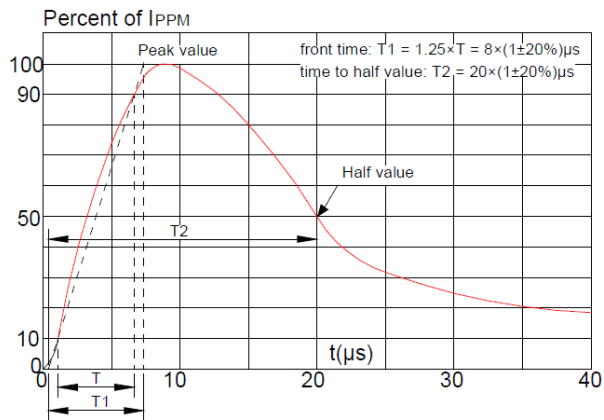
## Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ( $t_P = 8/20\mu S$ )	$P_{PK}$	3200	W
Peak Pulse Current ( $t_P = 8/20\mu S$ )	$I_{pp}$	160	A
ESD according to IEC61000-4-2 air discharge	$V_{ESD}$	$\pm 30$	kV
ESD according to IEC61000-4-2 contact discharge		$\pm 30$	kV
Lead Soldering Temperature	$T_L$	260 (10 sec)	$^{\circ}C$
Operating Temperature	$T_{OP}$	-55 to +125	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55 to +150	$^{\circ}C$

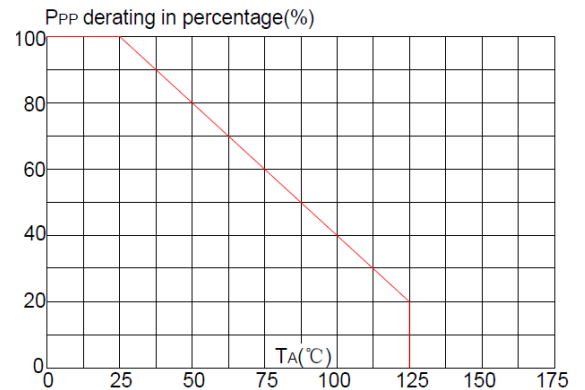
## Electrical Characteristics ( $T_a=25^{\circ}C$ , unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Stand-off Voltage	$V_{RWM}$				4.5	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1mA$	4.6	5.2	6.4	V
Reverse Leakage Current	$I_R$	$V_{RWM}=4.5V$			1	$\mu A$
Clamping Voltage	$V_C$	$I_{PP}=50A$ $t_P = 8/20\mu s$		8.5	11	V
Clamping Voltage	$V_C$	$I_{PP}=100A$ $t_P = 8/20\mu s$		12	14	V
Clamping Voltage	$V_C$	$I_{PP}=160A$ $t_P = 8/20\mu s$		17	20	V
Junction Capacitance	$C_j$	$V_R=0V$ $f = 1MHz$		300	500	pF

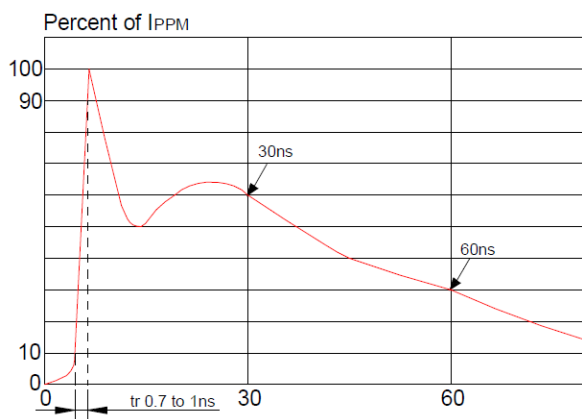
## Typical Characteristics (Ta=25℃, unless otherwise noted)



Pulse Waveform (8/20us)

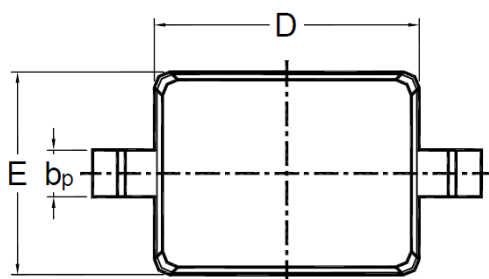
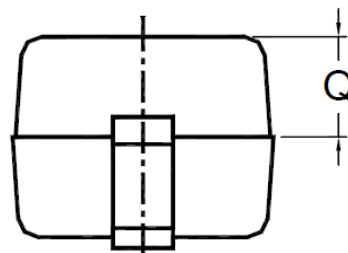
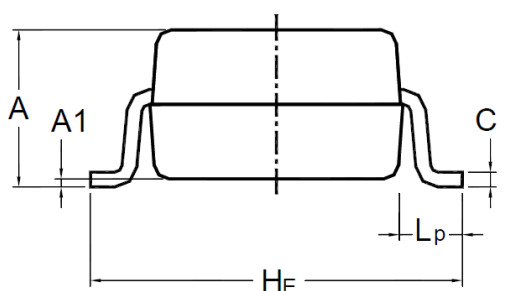


Pulse Derating Curve



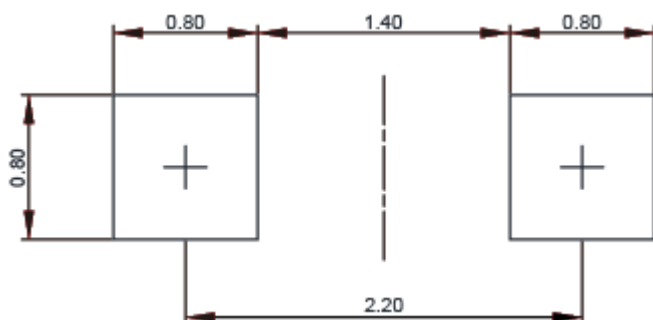
ESD Clamping(8kV Contact Discharge )

## Package Outline Dimensions (SOD323)



Dim	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.031	0.043	0.8	1.0
A <sub>1</sub>	0.000	0.004	0	0.1
b <sub>p</sub>	0.010	0.016	0.25	0.4
C	0.000	0.006	0	0.15
D	0.063	0.071	1.6	1.8
E	0.045	0.053	1.15	1.35
H <sub>E</sub>	0.091	0.110	2.3	2.8
L <sub>P</sub>	0.004	0.020	0.1	0.5
Q	0.012	0.020	0.3	0.5

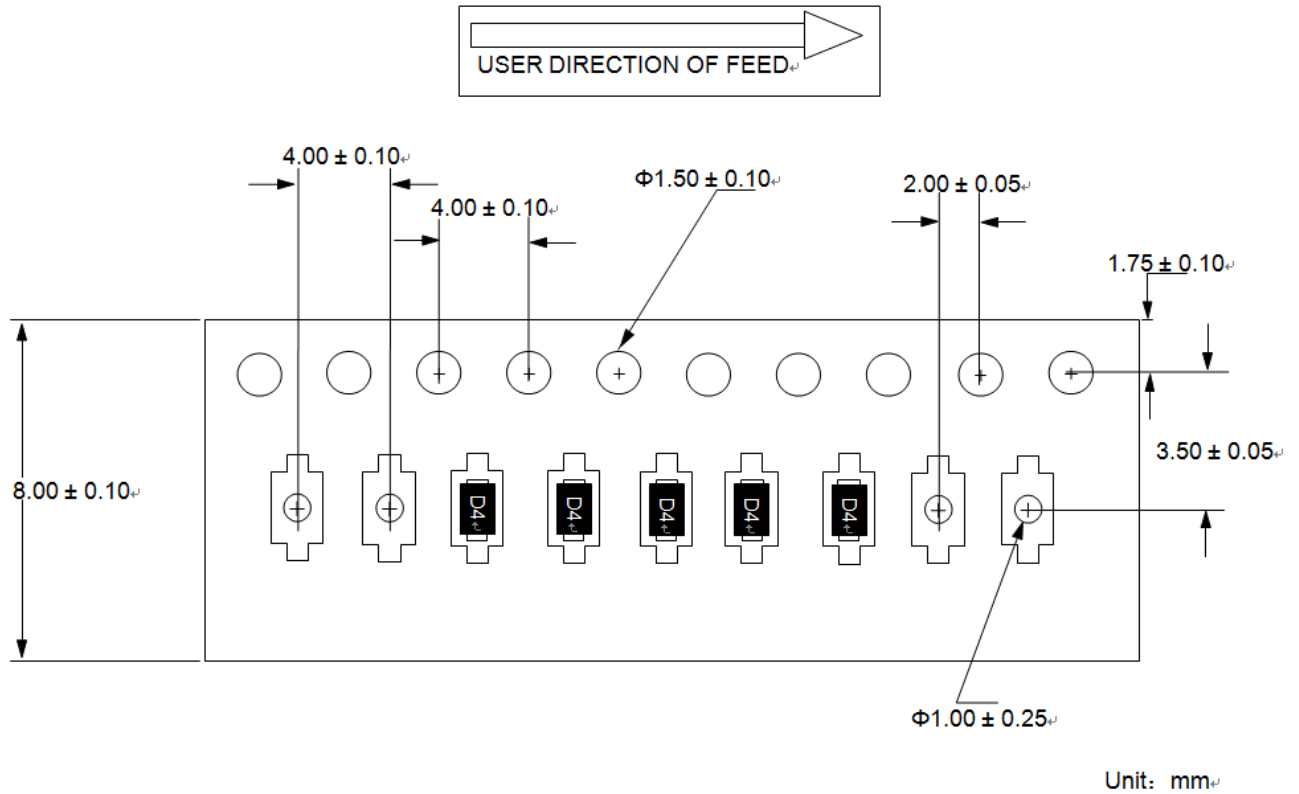
## Recommend Land Pattern (Unit: mm)



Note:

This recommended land pattern is for reference purpose only.

## Load With Information



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